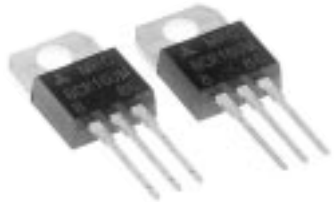


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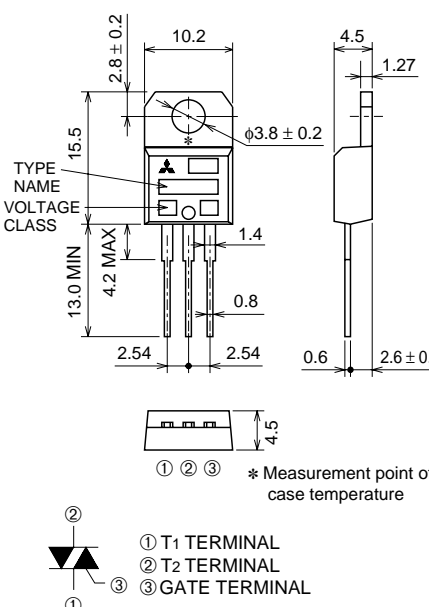
MEDIUM POWER USE  
INSULATED TYPE, GLASS PASSIVATION TYPE

**BCR16UM**



- IT (RMS) ..... 16A
- VDRM ..... 400V/600V
- IFGT I, IRGT I, IRGT III ..... 15mA
- V<sub>iso</sub> ..... 1500V

**OUTLINE DRAWING** Dimensions  
in mm



TYPE NAME  
VOLTAGE CLASS

① ② ③ \* Measurement point of case temperature

① T1 TERMINAL  
② T2 TERMINAL  
③ GATE TERMINAL

TO-220

## APPLICATION

Light dimmer

## MAXIMUM RATINGS

Symbol	Parameter	Voltage class		Unit
		8	12	
VDRM	Repetitive peak off-state voltage*1	400	600	V
VDSM	Non-repetitive peak off-state voltage*1	500	720	V

Symbol	Parameter	Conditions	Ratings	Unit
IT (RMS)	RMS on-state current	Commercial frequency, sine full wave 360° conduction, T <sub>c</sub> =79°C*3	16	A
ITSM	Surge on-state current	60Hz sinewave 1 full cycle, peak value, non-repetitive	170	A
I <sup>2</sup> <sub>t</sub>	I <sup>2</sup> <sub>t</sub> for fusing	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current	121	A <sup>2</sup> s
PGM	Peak gate power dissipation		5	W
PG (AV)	Average gate power dissipation		0.5	W
VGM	Peak gate voltage		10	V
IGM	Peak gate current		2	A
T <sub>j</sub>	Junction temperature		-40 ~ +125	°C
T <sub>stg</sub>	Storage temperature		-40 ~ +125	°C
—	Weight	Typical value	2.3	g
V <sub>iso</sub>	Isolation voltage	T <sub>a</sub> =25°C, AC 1 minute, T1 · T2 · G terminal to case	1500	V

\*1. Gate open.

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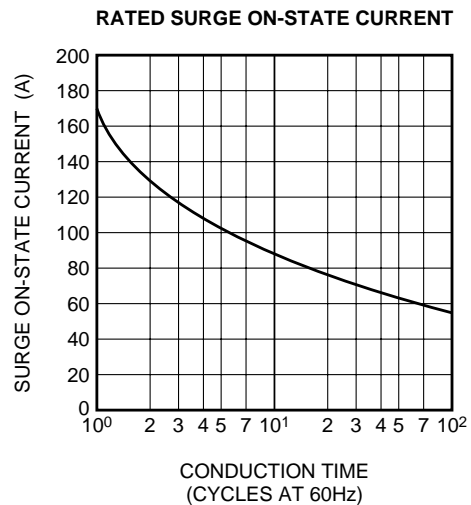
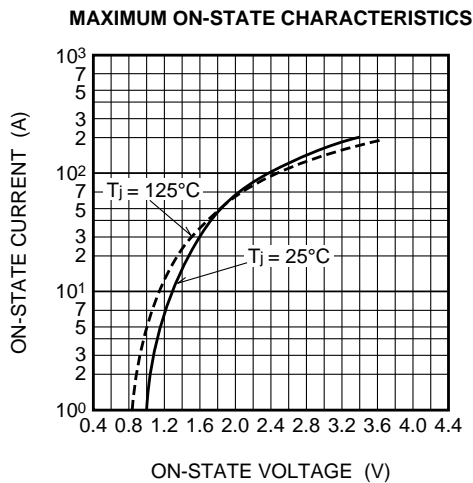
MEDIUM POWER USE  
INSULATED TYPE, GLASS PASSIVATION TYPE

## ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit	
			Min.	Typ.	Max.		
IDRM	Repetitive peak off-state current	T <sub>j</sub> =125°C, V <sub>DRM</sub> applied	—	—	2.0	mA	
V <sub>TM</sub>	On-state voltage	T <sub>c</sub> =25°C, I <sub>TM</sub> =25A, Instantaneous measurement	—	—	1.5	V	
V <sub>FGT I</sub>	Gate trigger voltage *2	T <sub>j</sub> =25°C, V <sub>D</sub> =6V, R <sub>L</sub> =6Ω, R <sub>G</sub> =330Ω	I	—	—	1.5	V
V <sub>RGT I</sub>			II	—	—	1.5	V
V <sub>RGT III</sub>			III	—	—	1.5	V
I <sub>FGT I</sub>	Gate trigger current *2	T <sub>j</sub> =25°C, V <sub>D</sub> =6V, R <sub>L</sub> =6Ω, R <sub>G</sub> =330Ω	I	—	—	15	mA
I <sub>RGT I</sub>			II	—	—	15	mA
I <sub>RGT III</sub>			III	—	—	15	mA
V <sub>GD</sub>	Gate non-trigger voltage	T <sub>j</sub> =125°C, V <sub>D</sub> =1/2V <sub>DRM</sub>	0.2	—	—	V	
R <sub>th(j-c)</sub>	Thermal resistance	Junction to case *3 *4	—	—	2.5	°C/W	

\*2. Measurement using the gate trigger characteristics measurement circuit.  
 \*3. Case temperature is measured at the T<sub>2</sub> terminal 1.5mm away from the molded case.  
 \*4. The contact thermal resistance R<sub>th(c-f)</sub> in case of greasing is 1.0°C/W.

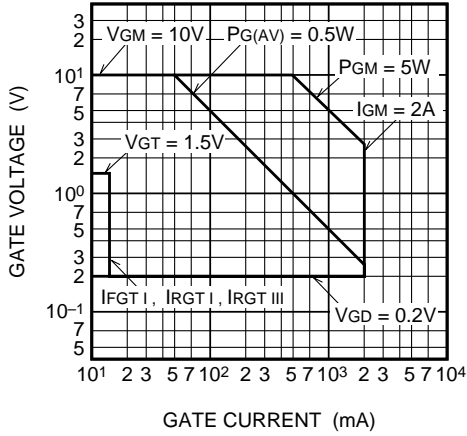
## PERFORMANCE CURVES



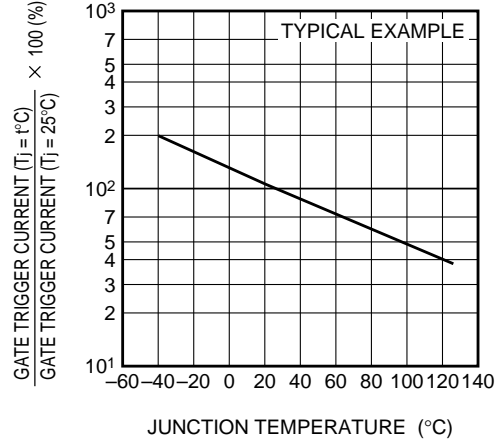
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MEDIUM POWER USE  
INSULATED TYPE, GLASS PASSIVATION TYPE

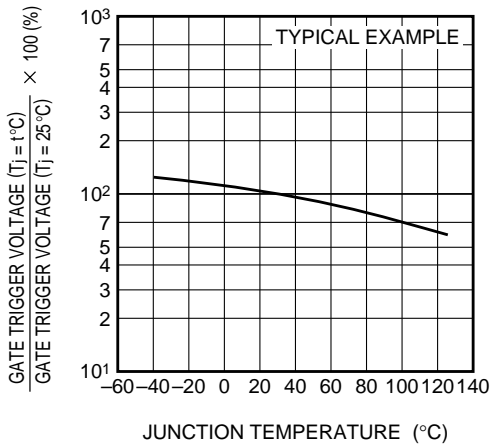
**GATE CHARACTERISTICS**



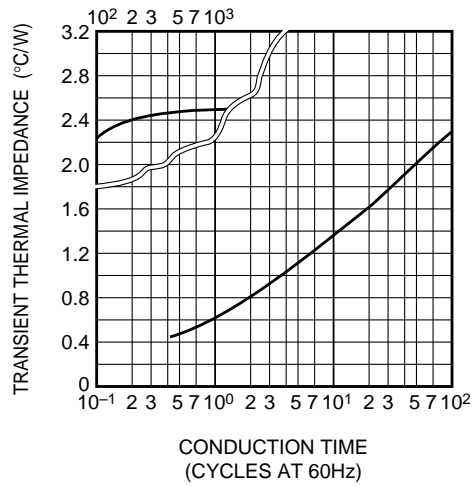
**GATE TRIGGER CURRENT VS. JUNCTION TEMPERATURE**



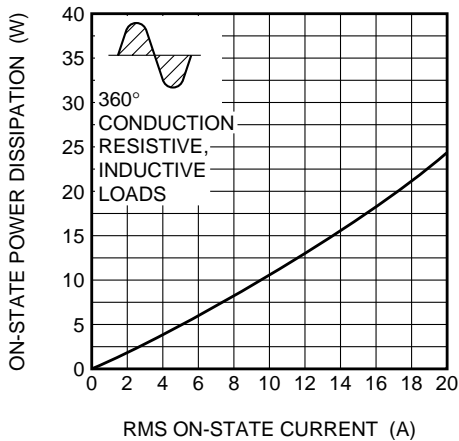
**GATE TRIGGER VOLTAGE VS. JUNCTION TEMPERATURE**



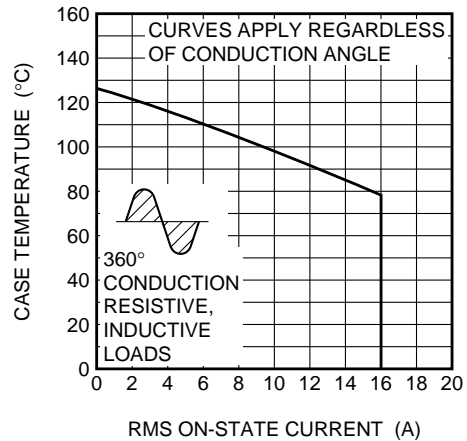
**MAXIMUM TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (JUNCTION TO CASE)**



**MAXIMUM ON-STATE POWER DISSIPATION**



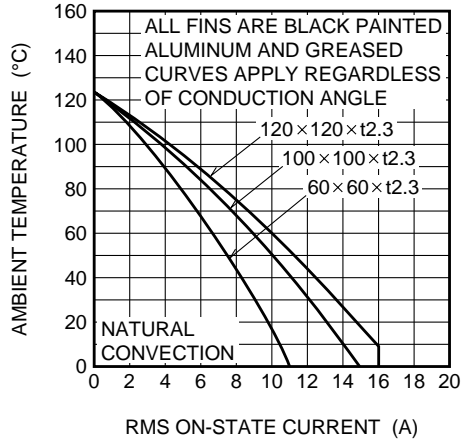
**ALLOWABLE CASE TEMPERATURE VS. RMS ON-STATE CURRENT**



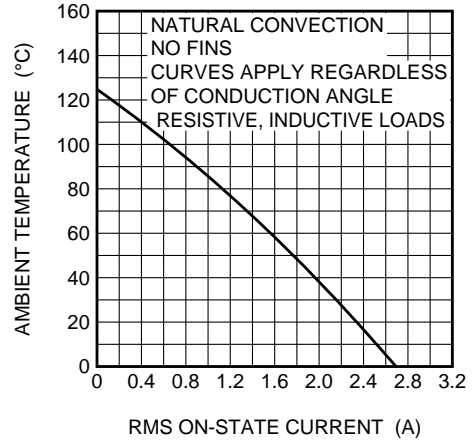
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MEDIUM POWER USE  
INSULATED TYPE, GLASS PASSIVATION TYPE

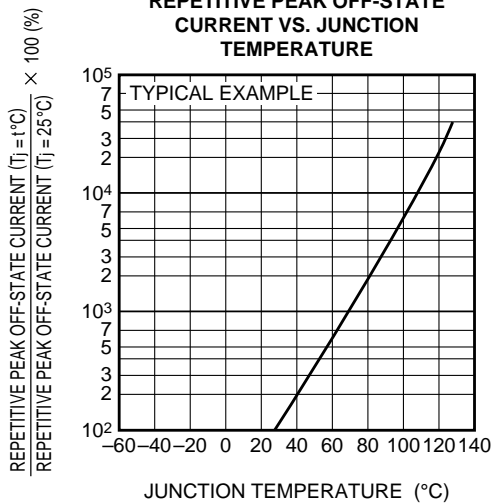
**ALLOWABLE AMBIENT TEMPERATURE VS. RMS ON-STATE CURRENT**



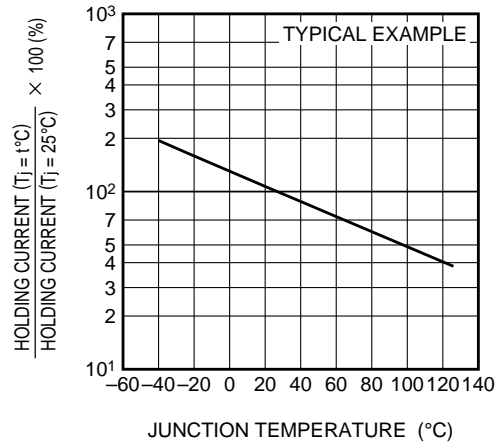
**ALLOWABLE AMBIENT TEMPERATURE VS. RMS ON-STATE CURRENT**



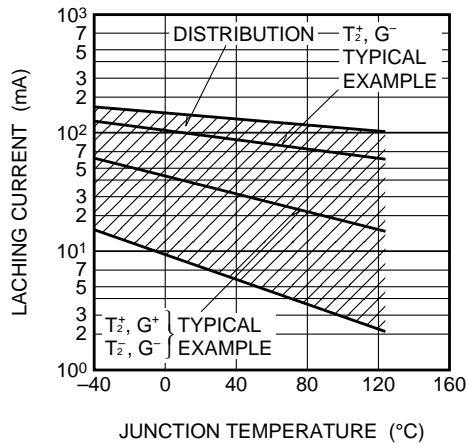
**REPETITIVE PEAK OFF-STATE CURRENT VS. JUNCTION TEMPERATURE**



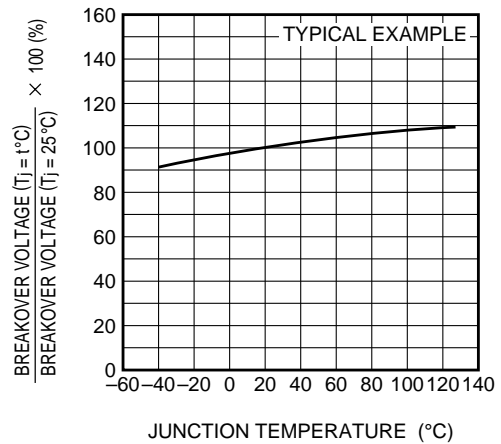
**HOLDING CURRENT VS. JUNCTION TEMPERATURE**



**LATCHING CURRENT VS. JUNCTION TEMPERATURE**



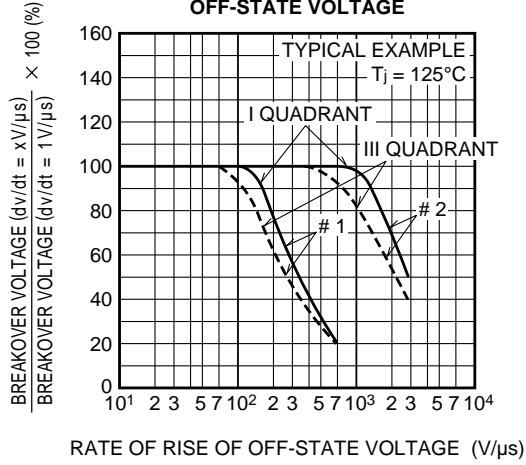
**BREAKOVER VOLTAGE VS. JUNCTION TEMPERATURE**



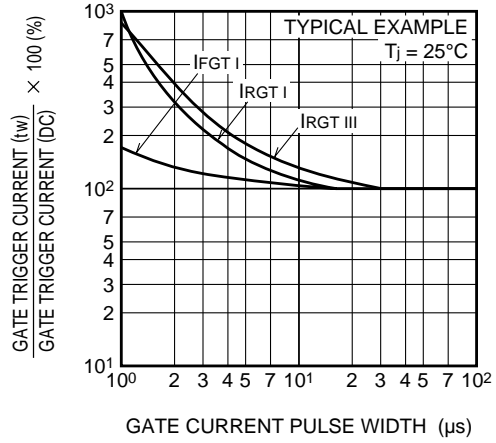
# BCR16UM

MEDIUM POWER USE  
INSULATED TYPE, GLASS PASSIVATION TYPE

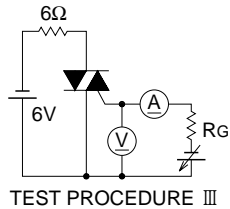
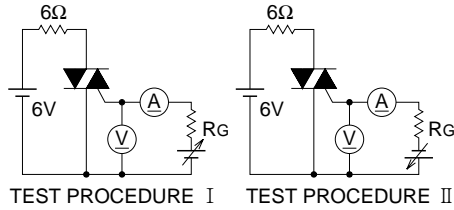
**BREAKOVER VOLTAGE VS.  
RATE OF RISE OF  
OFF-STATE VOLTAGE**



**GATE TRIGGER CURRENT VS.  
GATE CURRENT PULSE WIDTH**



**GATE TRIGGER CHARACTERISTICS TEST CIRCUITS**





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